CLAIMS

- 1-20. (Cancelled)
- 21. (Currently Amended) A multistage differential amplifier, comprising:
- (a)—a first amplifier stage, said the first amplifier stage including:
- (i)—a first differential pair of input transistors with loads coupled to a supply voltage through a first common-mode transistor; and
- (ii)—a first pair of emitter-follower output transistors coupled to said the first differential pair of input transistors;
- (b)—a second amplifier stage, said the second amplifier stage including:
- a second differential pair of input transistors with loads coupled to said the supply voltage through a second common-mode transistors; and
- (ii)—a second pair of emitter-follower output transistors coupled to said-the second differential pair of input transistors, wherein said-the second differential pair of input transistors is coupled to said-the first pair of emitter-follower output transistors; and
- (e) —a voltage regulator coupled to control said-the first common-mode transistor, said-the voltage regulator including;
 - (i)—a differential amplifier with a first input from a reference voltage, a second input from a temperature responsive unit, and an output to a third transistor connected between a supply voltage and said-the temperature responsive unit; and
 - (ii)—a regulated voltage output locus-node between said-the third transistor and said-the temperature responsive unit, wherein said-the temperature responsive unit includes in series a first resistor, a second resistor, and a diode-connected transistor having a voltage-temperature response similar to that of each of the first pair of emitter-follower output transistors in the first amplifier stage.
- (Currently Amended) The amplifier of claim 21, wherein (i) said-the first resistor is between said-the output locus node and said-the diode-connected transistor, said-the diode-connected transistor is between said-the first resistor and said-the second resistor, and

said-the second resistor is between said-the diode-connected transistor and ground, and (ii) said-the input from a temperature responsive unit connects between said-the diode-connected transistor and said-the second resistor.

- 23. (Currently Amended) Th e amplifier of claim 21, wherein (i) said-the diode-connected transistor is between said-the output locus-node and said-the first resistor, first resistor is between said-the diode-connected transistor and said-the second resistor, and said-the second resistor is between said-the first resistor and ground, and (ii) said-the input from a temperature responsive unit connects between said-the first resistor and said-the second resistor.
 - 24. (Currently Amended) A multistage differential amplifier[[,]] comprising:
 - (a)—a first amplifier stage, said-the first amplifier stage including:
 - a first differential pair of input NPN bipolar transistors with loads coupled to a supply voltage through a first common-mode PMOS transistor; and
 - (ii) a first pair of emitter-follower output NPN bipolar transistors coupled to said-the first differential pair of input transistors;
 - (b)—a second amplifier stage, said-the second amplifier stage including:
 - a second differential pair of input transistors with loads coupled to said the supply voltage through a second common-mode transistors; and
 - (ii)—a second pair of emitter-follower output transistors coupled to said-the second differential pair of input transistors, wherein said-the second differential pair of input transistors is coupled to said-the first pair of emitter-follower output transistors; and
- (e) —a voltage regulator coupled to control said-the first common-mode transistor, said-the voltage regulator including;
 - (i)—a differential amplifier with a first input from a reference voltage, a second input from a temperature responsive unit, and an output to a third transistor connected between a supply voltage and said-the temperature responsive unit; and
 - (ii)—a regulated voltage output locus node between said the third transistor and said the temperature responsive unit, wherein said the temperature responsive

unit includes in series a first resistor, a second resistor, and a diode-connected NPN bipolar transistor.

- (Currently Amended) The amplifier of claim 24, wherein said the voltage regulator
 is coupled to control said the second common-mode transistor.
- 26. (Currently Amended) The amplifier of claim 25, further comprising: (a)—a third amplifier stage, said-the third amplifier stage including:
- (i) —a third differential pair of input transistors with loads coupled to said-the supply voltage through a third common-mode transistor; and
- (ii)—a third pair of emitter-follower output transistors coupled to said—the third differential pair of input transistors, wherein said—the third differential pair of input transistors is coupled to said—the second pair of emitter-follower output transistors.
- 27. (Currently Amended) The amplifier of claim 21, wherein seid-the voltage regulator is coupled to control seid-the second common-mode transistor[[:]], and wherein the diode-connected transistor has a voltage-temperature response similar to that of each of the second pair of emitter-follower output transistors in the second amplifier stage.
- 28. (Currently Amended) The amplifier of claim 27, further comprising: (a) a third amplifier stage, said the third amplifier stage including;
- (i)—a third differential pair of input transistors with loads coupled to said-the supply voltage through a third common-mode transistor; and
- (ii)—a third pair of emitter-follower output transistors coupled to <u>said—the</u> third differential pair of input transistors, wherein <u>said-the</u> third differential pair of input transistors is coupled to <u>said-the</u> second pair of emitter-follower output transistors.